



60V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max Tc = +25°C
60V	65mΩ @ V _{GS} = 10V	27A
	$79m\Omega$ @ V _{GS} = 4.5V	24A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- Power Management Functions
- DC-DC Converters

Features and Benefits

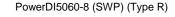
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low Input Capacitance
- Wettable Flank for Improved Optical Inspections
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotive-products/.

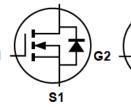
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.
 - https://www.diodes.com/quality/product-definitions/
- An Automotive-Compliant Part is Available Under Separate Datasheet (DMNH6065SPDWQ)

Mechanical Data

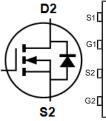
- Case: PowerDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)

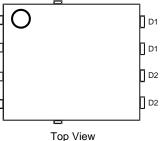






D1





Top View

Bottom View

Equivalent Circuit

Pin Configuration

Ordering Information (Note 4)

Part Number	Case	Packaging
DMNH6065SPDW-13	PowerDI5060-8 (SWP) (Type R)	2500 / Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information



⊃¦¦= Manufacturer's Marking NH6065SPDW = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 20 = 2020) WW = Week (01 to 53)

Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	60	V	
Gate-Source Voltage	V _{GSS}	±20	V	
Continuous Drain Current, V _{GS} = 10V (Note 6)	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	lo	27 19	А
Maximum Body Diode Forward Current (Note 6)	Is	27	Α	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	108	А	
Pulsed Source Current (10µs Pulse, Duty Cycle = 1%)	lsм	108	Α	
Avalanche Current, L = 1mH	Ias	13.3	Α	
Avalanche Energy, L = 1mH	E _{AS}	89	mJ	

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Thermal Resistance, Junction to Ambient (Note 5)		$R_{\theta JA}$	62	°C/W
Total Power Dissipation	T _A = +25°C	PD	2.4	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	2.2	°C/W
Total Power Dissipation	T _C = +25°C	P _D	68	W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes:

^{5.} Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate; measured with 1 channel active.

^{6.} Thermal resistance from junction to solder point (on the exposed drain pin); measured with 1 channel active.



Electrical Characteristics (@Tc = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	60	_	_	V	$V_{GS} = 0V, I_{D} = 250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	V _{DS} = 60V, V _{GS} = 0V	
Gate-Source Leakage	Igss	_	_	±100	nA	Vgs = ±20V, Vps = 0V	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	1	_	3	V	V _{DS} = V _{GS} , I _D = 250µA	
Static Drain-Source On-Resistance	Descent	_	53	65	mΩ	Vgs = 10V, ID = 15A	
Static Drain-Source On-Resistance	RDS(ON)	_	68	79	11122	Vgs = 4.5V, ID = 7.5A	
Diode Forward Voltage	V _{SD}	_	0.8	1.3	V	$V_{GS} = 0V, I_S = 2.6A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	466	_		V _{DS} = 25V, V _{GS} = 0V, f = 1.0MHz	
Output Capacitance	Coss	_	124	_	pF		
Reverse Transfer Capacitance	C _{rss}	_	9.9	_		1 - 1.0001112	
Gate Resistance	Rg	_	3.3	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1.0MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	4.6	_			
Total Gate Charge (V _{GS} = 10V)	Qg	_	9.5	_	nC	V _{DS} = 30V, I _D = 20A	
Gate-Source Charge	Qgs	_	1.3	_	110	VDS = 30V, ID = 20A	
Gate-Drain Charge	Qgd	_	2.9	_			
Turn-On Delay Time	tD(ON)	_	3.3	_		V _{DD} = 30V, V _{GS} = 10V,	
Turn-On Rise Time	t _R	_	4.6	_	ns		
Turn-Off Delay Time	tD(OFF)	_	12.6	_	115	$R_G = 4.7\Omega$, $I_D = 20A$	
Turn-Off Fall Time	tF	_	4.3	_			
Body Diode Reverse Recovery Time	trr	_	24	_	ns	IF = 20A, di/dt = 100A/µs	
Body Diode Reverse Recovery Charge	Q _{RR}	_	20	_	nC	I _F = 20A, di/dt = 100A/µs	

Notes:

^{7.} Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to product testing.



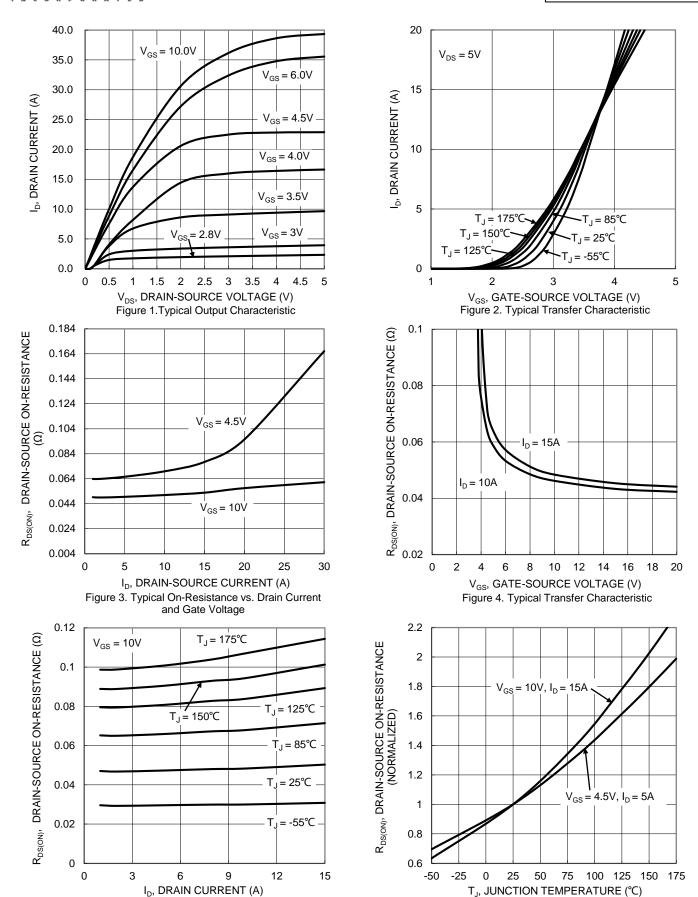


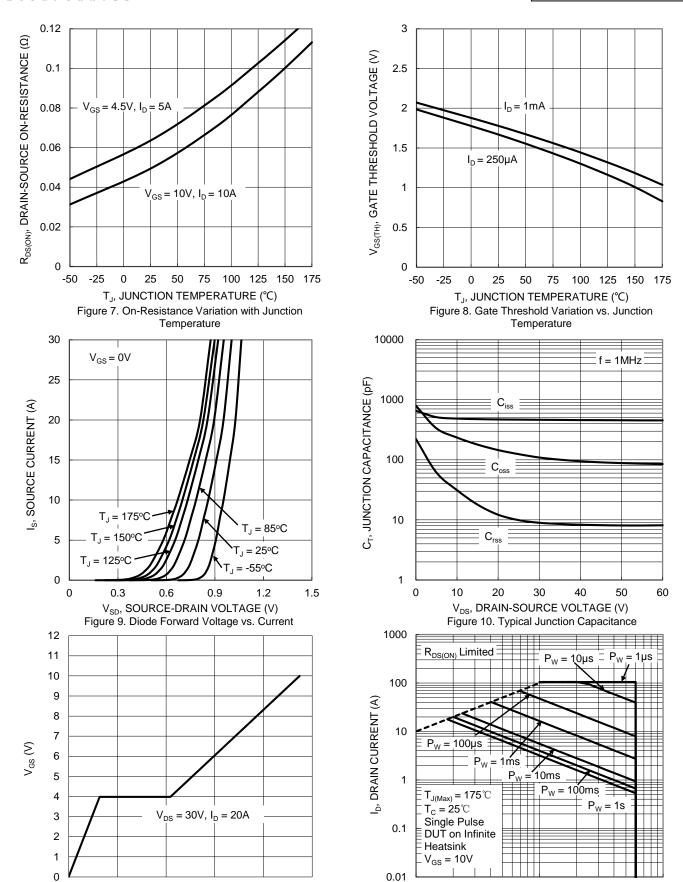
Figure 5. Typical On-Resistance vs. Drain Current and

Junction Temperature

Figure 6. On-Resistance Variation with Junction

Temperature





0

2

6

 Q_g (nC)

Figure 11. Gate Charge

8

10

100

10

V_{DS}, DRAIN-SOURCE VOLTAGE (V)

Figure 12. SOA, Safe Operation Area



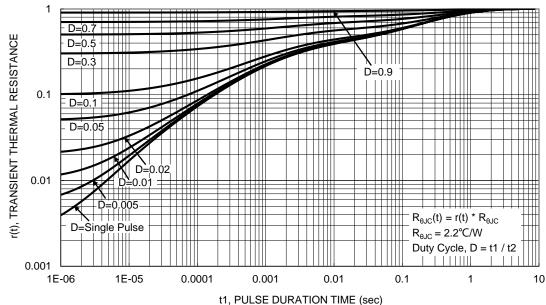
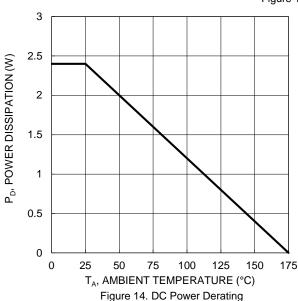


Figure 13. Transient Thermal Resistance



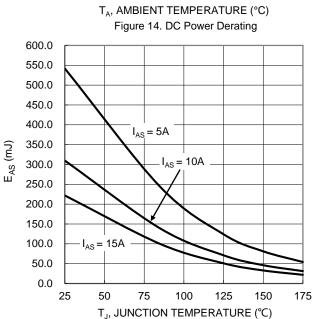
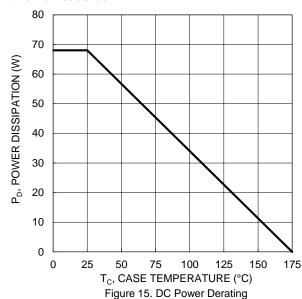


Figure 16. E_{AS} vs T_J

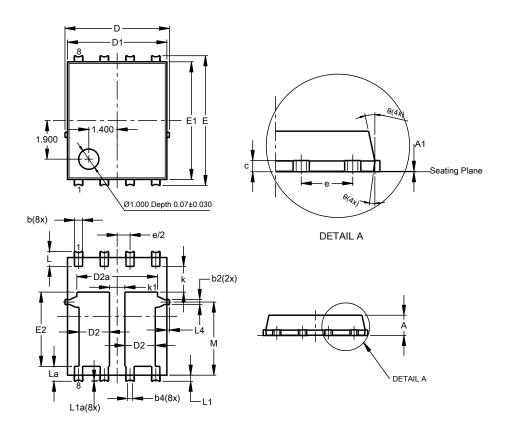




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8 (SWP) (Type R)

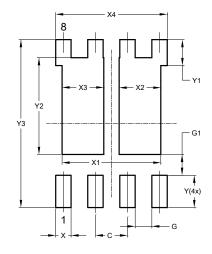


Pov	PowerDI5060-8 (SWP) (Type R)					
Dim	Min	Max	Тур			
Α	0.90	1.10	1.00			
A1	0	0.05				
b	0.30	0.50	0.41			
b2	0.20	0.35	0.25			
b4		.25REF				
С	0.230	0.330	0.277			
D		.15 BS0				
D1	4.70	5.10	4.90			
D2	1.40	1.60	1.50			
D2a	3.78	4.18	3.98			
Е	6	.40 BS0				
E1	5.60	6.00	5.80			
E2	3.46	3.86	3.66			
е		.27BSC	5			
k	1.05					
k1	0.56					
L	0.635	0.835	0.735			
La	0.635	0.835	0.735			
L1	0.200	0.400	0.300			
L1a	0.050REF					
L4	0.025	0.225	0.125			
M	3.205	4.005	3.605			
θ	10°	12°	11°			
θ1	6°	8°	7°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8 (SWP) (Type R)



Value		
(in mm)		
1.270		
0.660		
0.820		
0.610		
3.910		
1.650		
1.650		
4.420		
1.270		
1.020		
3.810		
6.610		



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